

NEW!
Two & Three
Section Models

MMIC

REFLECTIONLESS FILTERS DICE

50Ω DC to 21 GHz

The Big Deal

- High Stopband rejection, up to 50 dB
- Patented design terminates stopband signals
- Pass band cut-off up to 11 GHz
- Stop band up to 26 GHz
- Excellent repeatability through IPD* process



X-Series

Available in Low Pass
and High Pass designs

Product Overview

Mini-Circuits' **X-Series** of reflectionless filters now includes 2- and 3-section models, giving you ultra-high rejection in the stopband – up to 50 dB! Reflectionless filters employ a patented filter topology which absorbs and terminates stopband signals internally rather than reflecting them back to the source. This new capability enables unique applications for filter circuits beyond those suited to traditional approaches. Traditional filters are reflective in the stopband, sending signals back to the source at 100% power. These reflections interact with neighboring components and often result in intermodulation and other interferences. By eliminating stopband reflections, reflectionless filters can readily be paired with sensitive devices and used in applications that otherwise require circuits such as isolation amplifiers or attenuators.

Key Features	Advantages
Easy integration with sensitive reflective components, e.g. mixers, multipliers	Reflectionless filters absorb unwanted signals, preventing reflections back to the source. This reduces generation of additional unwanted signals without the need for extra components like attenuators, improving system dynamic range and saving board space.
High stopband rejection, up to 50 dB	Ideal for applications where suppression of strong spurious signals and intermodulation products is needed.
Enables stable integration of wideband amplifiers	Because reflectionless filters maintain good impedance in the stopband; they can be integrated with high gain, wideband amplifiers without the risk of creating instabilities in these out of band regions.
Cascadable	Reflectionless filters can be cascaded in multiple sections to provide sharper and higher attenuation, while also preventing any standing waves that could affect passband signals. Low & highpass filters can be cascaded to realize bandpass filters.
Excellent power handling in a tiny surface mount device up to 7W in passband	High power handling extends the usability of these filters to the transmit path for inter-stage filtering.
Excellent repeatability of RF performance	Through semiconductor IPD process, X-series filters are inherently repeatable for large volume production.
Excellent stability over temperature	With ± 0.3 dB variation over temperature ideal for use in wide temperature range applications without the need for additional temperature compensation.
Operating temperature up to 105°C	Suitable for operation close to high power components.

*IPD – Integrated Passive Device, is a GaAs semiconductor process



Reflectionless Low Pass Filter Die

XLF-172H-D+

50Ω DC to 2000 MHz

Features

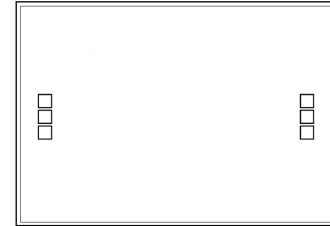
- Match to 50Ω in the stop band, eliminates undesired reflections
- Cascadable
- Excellent stopband rejection, 47 dB typ.
- Temperature stable, up to 105°C
- Protected by US Patents 8,392,495; 9,705,467, additional patent pending
- Protected by China Patent 201080014266.1
- Protected by Taiwan Patent I581494

Applications

- Cellular, PCS
- GPS
- Radio astronomy
- Telemetry

General Description

Mini-Circuits' XLF-172H-D+ three-section reflectionless filter Die employs a novel filter topology which absorbs and terminates stop band signals internally rather than reflecting them back to the source. This new capability enables unique applications for filter circuits beyond those suited to traditional approaches. Traditional filters are reflective in the stop band, sending signals back to the source at 100% of the power level. These reflections interact with neighboring components and often result in inter-modulation and other interferences. Reflectionless filters eliminate stop band reflections, allowing them to be paired with sensitive devices and used in applications that otherwise require circuits such as isolation amplifiers or attenuators.

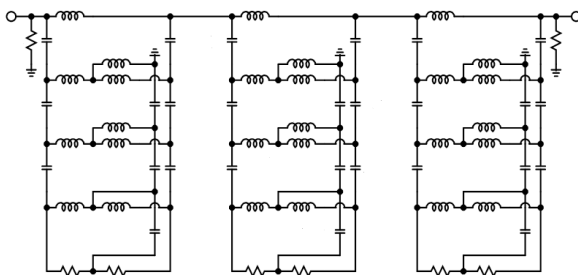


+RoHS Compliant

The +Suffix identifies RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications

Ordering Information: Refer to Last Page

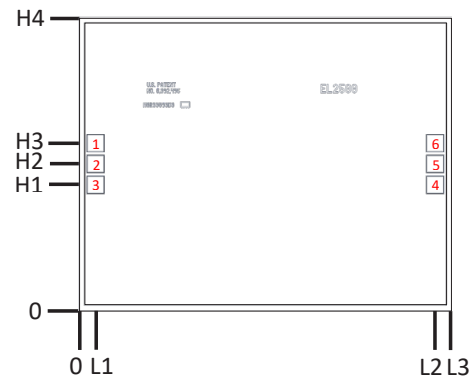
Simplified Schematic and Pad description



Pad#	Description
2	RF-IN
5	RF-OUT
1,3,4,6	Ground
Die bottom	Ground

Note: 1. Bond Pad material - Gold
2. Bottom of Die - Gold plated

Bonding Pad Position



Dimensions in μm, Typical

L1	L2	L3	H1	H2	H3	H4	Thickness	Bond pad size
80	1720	1800	610	710	810	1420	100	78 x 78

Electrical Specifications¹ at 25°C

Parameter	F#	Frequency (MHz)	Min.	Typ.	Max.	Unit	
Pass Band	Insertion Loss	DC - F1	DC - 2000	—	1.7	—	dB
	Frequency Cut-off	F2	2350	—	3.0	—	
	VSWR	DC - F1	DC - 2000	—	1.3	—	:1
Stop Band	Rejection	F3 - F3'	3600 - 3800	—	28	—	dB
		F3' - F4	3800 - 11000	—	47	—	
		F4 - F5	11000 - 20000	—	46	—	
	VSWR	F3 - F3'	3600 - 3800	—	1.2	—	:1
		F3' - F4	3800 - 11000	—	1.4	—	
		F4 - F5	11000 - 20000	—	1.5	—	

¹ Measured on Mini-Circuits Characterization Test Board . Die packaged in 4x4mm, 24-lead MCLP package and soldered on TB-952-172H+.

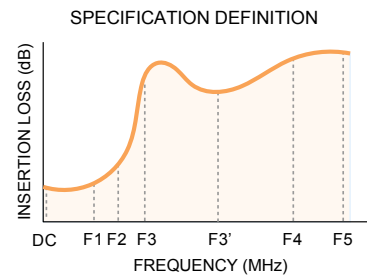
Absolute Maximum Ratings⁴

Parameter	Ratings
Operating Temperature	-55°C to +105°C
RF Power Input, Passband (DC-F1) ²	7.9W at 25°C
RF Power Input, Stopband (F2-F5) ³	1.58W at 25°C

² Passband rating derates linearly to 3.9W at 105°C ambient

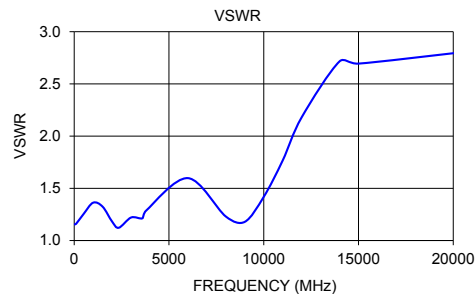
³ Stopband rating derates linearly to 0.75W at 105°C ambient

⁴ Permanent damage may occur if any of these limits are exceeded.

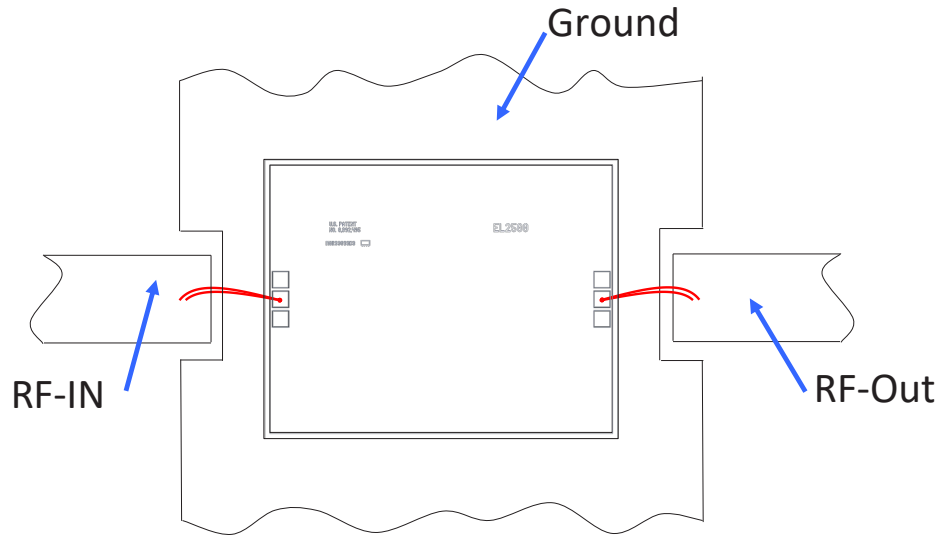


Typical Performance Data at 25°C¹

Frequency (MHz)	Insertion Loss (dB)	VSWR (:1)
10	1.15	1.16
100	1.16	1.16
500	1.30	1.26
1000	1.61	1.36
1500	1.98	1.32
2000	2.45	1.18
2350	2.99	1.12
3000	5.58	1.22
3600	20.35	1.21
3800	42.42	1.29
6000	36.18	1.60
8000	51.77	1.23
9000	65.37	1.18
10000	61.29	1.42
11000	55.48	1.77
12000	50.73	2.18
14000	47.75	2.72
15000	46.17	2.69
20000	50.12	2.79



Assembly Diagram



Note: Ground bond wires are optional.

Assembly and Handling Procedure

- 1. Storage**
Dice should be stored in a dry nitrogen purged desiccators or equivalent.
- 2. ESD**
MMIC Gallium Arsenide (GaAs) filter dice are susceptible to electrostatic and mechanical damage. Die are supplied in antistatic protected material, which should be opened in clean room conditions at an appropriately grounded anti-static workstation. Devices need careful handling using correctly designed collets, vacuum pickup tips or sharp antistatic tweezers to deter ESD damage to dice.
- 3. Die Attach**
The Die mounting surface must be clean and flat. Using conductive silver filled epoxy, recommended epoxies are DieMat DM6030Hk-PT/H579/H579 or Ablestik 84-1LMISR4. Apply sufficient epoxy to meet required epoxy bond line thickness, epoxy fillet height and epoxy coverage around total Die periphery. Parts shall be cured in a nitrogen filled atmosphere per manufacturer's cure condition. It is recommended to use antistatic Die pick up tools only.
- 4. Wire Bonding**
Bond pad openings in the surface passivation above the bond pads are provided to allow wire bonding to the dice gold bond pads. Thermosonic bonding is used with minimized ultrasonic content. Bond force, time, ultrasonic power and temperature are all critical parameters. Suggested wire is pure gold, 1 mil diameter. Bonds must be made from the bond pads on the Die to the package or substrate. All bond wires should be kept as short as low as reasonable to minimize performance degradation due to undesirable series inductance.

MMIC Reflectionless Low Pass Filter Die XLF-172H-D+

Typical Performance Data

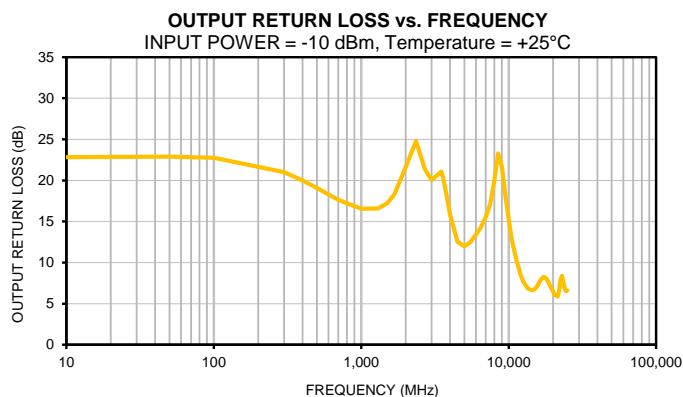
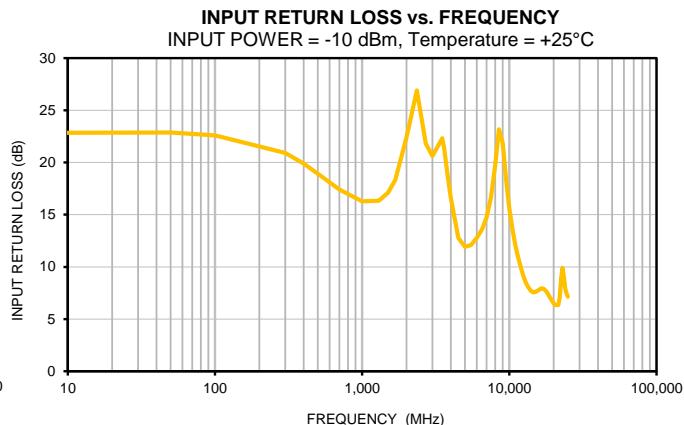
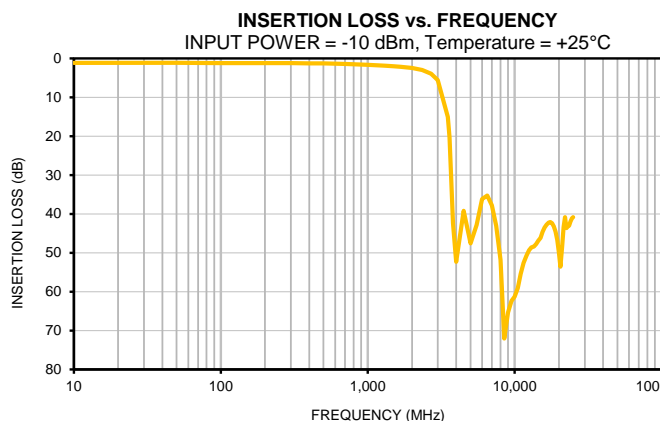
Test Condition @ Temperature = +25°C

FREQ. (MHz)	INSERTION LOSS (dB)	INPUT RETURN LOSS (dB)	OUTPUT RETURN LOSS (dB)
10	1.15	22.85	22.84
50	1.15	22.88	22.89
100	1.16	22.61	22.76
300	1.21	20.90	21.00
400	1.25	19.89	20.00
500	1.30	18.92	19.08
700	1.41	17.42	17.64
1000	1.61	16.28	16.56
1300	1.83	16.35	16.59
1500	1.98	17.12	17.23
1680	2.13	18.33	18.30
2000	2.45	22.41	21.60
2350	2.99	26.90	24.79
2700	3.96	21.83	21.35
3000	5.58	20.61	20.06
3500	15.04	22.33	21.06
3600	20.35	21.51	20.34
3800	42.42	18.92	18.02
4000	52.33	16.58	15.90
4500	39.23	12.79	12.53
5000	47.59	11.92	12.00
5500	42.81	12.07	12.50
6000	36.18	12.76	13.40
6500	35.27	13.59	14.33
7000	37.79	14.72	15.53
7500	43.06	16.62	17.19
8000	51.77	19.73	19.98
8500	72.05	23.18	23.29
9000	65.37	21.87	21.71
9500	62.41	18.33	18.22
10000	61.29	15.62	15.24
10500	59.06	13.61	12.87
11000	55.41	12.06	11.15
11500	52.60	10.86	9.74
12000	50.73	9.84	8.61
12500	49.38	9.03	7.77
13000	48.59	8.44	7.26
13500	48.37	7.99	6.88
14000	47.71	7.69	6.71
14500	46.88	7.57	6.64
15000	46.16	7.59	6.77
15500	44.65	7.69	7.01
16000	43.50	7.82	7.46
16500	42.76	7.94	7.90
17000	42.25	7.91	8.20
17500	42.12	7.77	8.25
18000	42.38	7.55	8.07
18500	43.19	7.25	7.70
19000	44.51	6.97	7.31
19500	46.69	6.75	6.89
20000	50.12	6.51	6.51
20500	53.55	6.35	6.09
21000	48.40	6.33	5.98
21500	43.42	6.36	5.87
22000	40.86	7.04	6.56
22500	43.65	8.87	7.96
23000	43.19	9.90	8.38
23500	43.05	8.90	7.51
24000	41.93	7.96	6.88
24500	41.11	7.43	6.53
25000	40.83	7.14	6.61
25500	40.82	6.88	6.69
26000	41.33	6.87	6.94

Note: "Test data of Die packaged in industry standard 4x4mm, 24-lead MCLP package"



Typical Performance Curves



Note: "Test data of Die packaged in industry standard 4x4mm, 24-lead MCLP package"



All Mini-Circuits products are manufactured under exacting quality assurance and control standards, and are capable of meeting published specifications after being subjected to any or all of the following physical and environmental test.

Specification	Test/Inspection Condition	Reference/Spec
Operating Temperature	-40° to 85° C or -40° to 105° C or -55° to 105° C or -45° to 105° C Ambient Environment	Refer to Individual Model Data Sheet
Storage Environment (Die)	-65° to 150°C	Individual Model Data Sheet
Storage Environment(Packaging)	-40° to 70°C and 40 to 60% humidity (In Factory Shipped Package)	